1. General description

NPN Resistor-Equipped Transistor (RET) family in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

<table>
<thead>
<tr>
<th>Type number</th>
<th>R1</th>
<th>R2</th>
<th>Package</th>
<th>PNP complement:</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>kΩ</td>
<td>kΩ</td>
<td>Nexperia</td>
<td>JEDEC</td>
</tr>
<tr>
<td>NHDTA144ET</td>
<td>10</td>
<td>10</td>
<td>SOT23</td>
<td>TO-236AB</td>
</tr>
<tr>
<td>NHDTA124ET</td>
<td>22</td>
<td>22</td>
<td></td>
<td>NHDTA124ET</td>
</tr>
<tr>
<td>NHDTA144ET</td>
<td>47</td>
<td>47</td>
<td></td>
<td>NHDTA144ET</td>
</tr>
</tbody>
</table>

2. Features and benefits

- 100 mA output current capability
- High breakdown voltage
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Digital applications
- Cost saving alternative for BC846 series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

Table 2. Quick reference data

\( T_{\text{amb}} = 25 \, ^{\circ} \text{C unless otherwise specified.} \)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_{\text{CEO}} )</td>
<td>collector-emitter voltage</td>
<td>open base</td>
<td>-</td>
<td>-</td>
<td>80</td>
<td>V</td>
</tr>
<tr>
<td>( I_O )</td>
<td>output current</td>
<td></td>
<td>-</td>
<td>-</td>
<td>100</td>
<td>mA</td>
</tr>
</tbody>
</table>
5. Pinning information

Table 3. Pinning

<table>
<thead>
<tr>
<th>Pin</th>
<th>Symbol</th>
<th>Description</th>
<th>Simplified outline</th>
<th>Graphic symbol</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>I</td>
<td>input (base)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>GND</td>
<td>GND (emitter)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>3</td>
<td>O</td>
<td>output (collector)</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>


6. Ordering information

Table 4. Ordering information

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package</th>
<th>Description</th>
<th>Version</th>
</tr>
</thead>
<tbody>
<tr>
<td>NHDT114ET</td>
<td>TO-236AB</td>
<td>plastic surface-mounted package; 3 leads</td>
<td>SOT23</td>
</tr>
<tr>
<td>NHDT124ET</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>NHDT144ET</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

7. Marking

Table 5. Marking

<table>
<thead>
<tr>
<th>Type number</th>
<th>Marking code [1]</th>
</tr>
</thead>
<tbody>
<tr>
<td>NHDT114ET</td>
<td>QG%</td>
</tr>
<tr>
<td>NHDT124ET</td>
<td>QK%</td>
</tr>
<tr>
<td>NHDT144ET</td>
<td>QM%</td>
</tr>
</tbody>
</table>

[1] % = placeholder for manufacturing site code
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). 

\( T_{\text{amb}} = 25 \, ^{\circ}\text{C} \) unless otherwise specified.

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_{\text{CBO}} )</td>
<td>collector-base voltage</td>
<td>open emitter</td>
<td>-</td>
<td>80</td>
<td>V</td>
</tr>
<tr>
<td>( V_{\text{CEO}} )</td>
<td>collector-emitter voltage</td>
<td>open base</td>
<td>-</td>
<td>80</td>
<td>V</td>
</tr>
<tr>
<td>( V_{\text{EBO}} )</td>
<td>emitter-base voltage</td>
<td>open collector</td>
<td>-</td>
<td>10</td>
<td>V</td>
</tr>
<tr>
<td>( V_{i} )</td>
<td>input voltage</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>NHDT114ET</td>
<td>-10</td>
<td>+40</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>NHDT124ET</td>
<td>-10</td>
<td>+60</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>NHDT144ET</td>
<td>-10</td>
<td>+80</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_{O} )</td>
<td>output current</td>
<td></td>
<td></td>
<td>100</td>
<td>mA</td>
</tr>
<tr>
<td>( P_{\text{tot}} )</td>
<td>total power dissipation</td>
<td>( T_{\text{amb}} \leq 25 , ^{\circ}\text{C} )</td>
<td>[1]</td>
<td>-</td>
<td>250</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>[2]</td>
<td>-</td>
<td>350</td>
</tr>
<tr>
<td>( T_{j} )</td>
<td>junction temperature</td>
<td></td>
<td></td>
<td>-</td>
<td>150</td>
</tr>
<tr>
<td>( T_{\text{amb}} )</td>
<td>ambient temperature</td>
<td></td>
<td></td>
<td>-55</td>
<td>150</td>
</tr>
<tr>
<td>( T_{\text{stg}} )</td>
<td>storage temperature</td>
<td></td>
<td></td>
<td>-65</td>
<td>150</td>
</tr>
</tbody>
</table>

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.

![Fig. 1. Power derating curves for SOT23 (TO-236AB)](image)

(1) FR4 PCB, 4-layer copper, standard footprint
(2) FR4 PCB, single-sided copper, standard footprint
9. Thermal characteristics

Table 7. Thermal characteristics

\( T_{\text{amb}} = 25 \, ^\circ\text{C} \) unless otherwise specified.

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>( R_{\text{th(j-a)}} )</td>
<td>thermal resistance from junction to ambient</td>
<td>in free air</td>
<td>[1]</td>
<td>-</td>
<td>-</td>
<td>500 K/W</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>[2]</td>
<td>-</td>
<td>-</td>
<td>358 K/W</td>
</tr>
<tr>
<td>( R_{\text{th(j-sp)}} )</td>
<td>thermal resistance from junction to solder point</td>
<td></td>
<td>-</td>
<td>-</td>
<td>130</td>
<td>K/W</td>
</tr>
</tbody>
</table>

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

FR4 PCB, single-sided copper, tin-plated and standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

FR4 PCB, 4-layer copper, tin-plated and standard footprint
# 10. Characteristics

Table 8. Characteristics  
\(T_{\text{amb}} = 25 \degree \text{C unless otherwise specified.}\)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>(V_{(BR)CBO})</td>
<td>collector-base breakdown voltage</td>
<td>(I_C = 100 \mu\text{A}; I_E = 0 \text{ A})</td>
<td>80</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>(V_{(BR)CEO})</td>
<td>collector-emitter breakdown voltage</td>
<td>(I_C = 2 \text{ mA}; I_B = 0 \text{ A})</td>
<td>80</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>(I_{CBO})</td>
<td>collector-base cut-off current</td>
<td>(V_{CB} = 80 \text{ V}; I_E = 0 \text{ A})</td>
<td>-</td>
<td>-</td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td>(I_{CEO})</td>
<td>collector-emitter cut-off current</td>
<td>(V_{CE} = 60 \text{ V}; I_B = 0 \text{ A})</td>
<td>-</td>
<td>-</td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td>(I_{EBO})</td>
<td>emitter-base cut-off current</td>
<td>(V_{EB} = 7 \text{ V}; I_C = 0 \text{ A})</td>
<td>-</td>
<td>-</td>
<td>600</td>
<td>µA</td>
</tr>
<tr>
<td>(h_{FE})</td>
<td>DC current gain</td>
<td>(V_{CE} = 5 \text{ V}; I_C = 10 \text{ mA})</td>
<td>50</td>
<td>-</td>
<td>-</td>
<td></td>
</tr>
<tr>
<td>(V_{CEsat})</td>
<td>collector-emitter saturation voltage</td>
<td>(I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA})</td>
<td>-</td>
<td>-</td>
<td>100</td>
<td>mV</td>
</tr>
<tr>
<td>(V_{I(\text{off})})</td>
<td>off-state input voltage</td>
<td>(V_{CE} = 5 \text{ V} ; I_C = 100 \mu\text{A})</td>
<td>-</td>
<td>1.15</td>
<td>0.8</td>
<td>V</td>
</tr>
<tr>
<td>(V_{I(on)})</td>
<td>on-state input voltage</td>
<td>(V_{CE} = 0.3 \text{ V} ; I_C = 10 \text{ mA})</td>
<td>2.5</td>
<td>1.8</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>(R_1)</td>
<td>bias resistor 1 (input)</td>
<td>(V_{CE} = 0.3 \text{ V} ; I_C = 10 \text{ mA})</td>
<td>7</td>
<td>10</td>
<td>13</td>
<td>kΩ</td>
</tr>
<tr>
<td>(R_{2/R1})</td>
<td>bias resistor ratio</td>
<td>(V_{CE} = 0.3 \text{ V} ; I_C = 10 \text{ mA})</td>
<td>0.8</td>
<td>1</td>
<td>1.2</td>
<td></td>
</tr>
<tr>
<td>(f_T)</td>
<td>transition frequency</td>
<td>(V_{CE} = 5 \text{ V} ; I_C = 10 \text{ mA})</td>
<td>-</td>
<td>170</td>
<td>-</td>
<td>MHz</td>
</tr>
<tr>
<td>(C_C)</td>
<td>collector capacitance</td>
<td>(V_{CB} = 10 \text{ V} ; I_E = I_B = 0 \text{ A})</td>
<td>-</td>
<td>-</td>
<td>2.5</td>
<td>pF</td>
</tr>
</tbody>
</table>

[1] See section "Test information" for resistor calculation and test conditions

Nexperia

NHDT114/124/144ET series

80 V, 100 mA NPN resistor-equipped transistors

---

**Fig. 4.** NHDT114ET: DC current gain as a function of collector current; typical values

<table>
<thead>
<tr>
<th>$\frac{V_{CE}}{I_C}$ (mA)</th>
<th>$h_{FE}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$10^1$</td>
<td>10</td>
</tr>
<tr>
<td>$10^2$</td>
<td>100</td>
</tr>
<tr>
<td>$10^3$</td>
<td>1000</td>
</tr>
</tbody>
</table>

$V_{CE} = 5$ V

(1) $T_{amb} = 100$ °C
(2) $T_{amb} = 25$ °C
(3) $T_{amb} = -40$ °C

---

**Fig. 5.** NHDT114ET: Collector current as a function of collector-emitter voltage; typical values

<table>
<thead>
<tr>
<th>$I_C (mA)$</th>
<th>$V_{CE} (V)$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$10^{-1}$</td>
<td>0.02</td>
</tr>
<tr>
<td>$10^0$</td>
<td>0.04</td>
</tr>
<tr>
<td>$10^1$</td>
<td>0.06</td>
</tr>
</tbody>
</table>

$T_{amb} = 25$ °C

---

**Fig. 6.** NHDT114ET: On-state input voltage as a function of collector current; typical values

<table>
<thead>
<tr>
<th>$V_{(on)} (V)$</th>
<th>$I_C (mA)$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$10^{-1}$</td>
<td>1</td>
</tr>
<tr>
<td>$10^0$</td>
<td>10</td>
</tr>
<tr>
<td>$10^1$</td>
<td>100</td>
</tr>
</tbody>
</table>

$V_{CE} = 0.3$ V

(1) $T_{amb} = -40$ °C
(2) $T_{amb} = 25$ °C
(3) $T_{amb} = 100$ °C

---

**Fig. 7.** NHDT114ET: Off-state input voltage as a function of collector current; typical values

<table>
<thead>
<tr>
<th>$V_{(off)} (V)$</th>
<th>$I_C (mA)$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$10^{-1}$</td>
<td>1</td>
</tr>
<tr>
<td>$10^0$</td>
<td>10</td>
</tr>
<tr>
<td>$10^1$</td>
<td>100</td>
</tr>
</tbody>
</table>

$V_{CE} = 5$ V

(1) $T_{amb} = -40$ °C
(2) $T_{amb} = 25$ °C
(3) $T_{amb} = 100$ °C
Nexperia

NHDTCL14/124/144ET series

80 V, 100 mA NPN resistor-equipped transistors

I<sub>C/I<sub>B</sub> = 20
(1) T<sub>amb</sub> = 100 °C
(2) T<sub>amb</sub> = 25 °C
(3) T<sub>amb</sub> = -40 °C

Fig. 8. NHDTCL114ET: Collector-emitter saturation voltage as a function of collector current; typical values

f = 1 MHz
T<sub>amb</sub> = 25 °C

Fig. 9. NHDTCL114ET: Collector capacitance as a function of collector-base voltage; typical values

V<sub>CE</sub> = 5 V
(1) T<sub>amb</sub> = 100 °C
(2) T<sub>amb</sub> = 25 °C
(3) T<sub>amb</sub> = -40 °C

Fig. 10. NHDTCL124ET: DC current gain as a function of collector current; typical values

T<sub>amb</sub> = 25 °C

Fig. 11. NHDTCL124ET: Collector current as a function of collector-emitter voltage; typical values
Nexperia

**NHDC114/124/144ET series**

80 V, 100 mA NPN resistor-equipped transistors

---

**Fig. 12.** NHDC124ET: On-state input voltage as a function of collector current; typical values

\[ V_{CE} = 0.3 \text{ V} \]

(1) \( T_{\text{amb}} = -40 ^\circ \text{C} \)

(2) \( T_{\text{amb}} = 25 ^\circ \text{C} \)

(3) \( T_{\text{amb}} = 100 ^\circ \text{C} \)

---

**Fig. 13.** NHDC124ET: Off-state input voltage as a function of collector current; typical values

\[ V_{CE} = 5 \text{ V} \]

(1) \( T_{\text{amb}} = -40 ^\circ \text{C} \)

(2) \( T_{\text{amb}} = 25 ^\circ \text{C} \)

(3) \( T_{\text{amb}} = 100 ^\circ \text{C} \)

---

**Fig. 14.** NHDC124ET: Collector-emitter saturation voltage as a function of collector current; typical values

\[ I_{C/I_B} = 20 \]

(1) \( T_{\text{amb}} = 100 ^\circ \text{C} \)

(2) \( T_{\text{amb}} = 25 ^\circ \text{C} \)

(3) \( T_{\text{amb}} = -40 ^\circ \text{C} \)

---

**Fig. 15.** NHDC124ET: Collector capacitance as a function of collector-base voltage; typical values

\[ f = 1 \text{ MHz} \]

\( T_{\text{amb}} = 25 ^\circ \text{C} \)
Nexperia

NHDT114/124/144ET series

80 V, 100 mA NPN resistor-equipped transistors

Fig. 16. NHDT144ET: DC current gain as a function of collector current; typical values

\[ V_{CE} = 5 \text{ V} \]
(1) \( T_{\text{amb}} = 100 \ ^\circ \text{C} \)
(2) \( T_{\text{amb}} = 25 \ ^\circ \text{C} \)
(3) \( T_{\text{amb}} = -40 \ ^\circ \text{C} \)

Fig. 17. NHDT144ET: Collector current as a function of collector-emitter voltage; typical values

\[ V_{CE} = 0.3 \text{ V} \]
(1) \( T_{\text{amb}} = -40 \ ^\circ \text{C} \)
(2) \( T_{\text{amb}} = 25 \ ^\circ \text{C} \)
(3) \( T_{\text{amb}} = 100 \ ^\circ \text{C} \)

Fig. 18. NHDT144ET: On-state input voltage as a function of collector current; typical values

\[ V_{CE} = 5 \text{ V} \]
(1) \( T_{\text{amb}} = -40 \ ^\circ \text{C} \)
(2) \( T_{\text{amb}} = 25 \ ^\circ \text{C} \)
(3) \( T_{\text{amb}} = 100 \ ^\circ \text{C} \)

Fig. 19. NHDT144ET: Off-state input voltage as a function of collector current; typical values
Nexperia

NHDTC114/124/144ET series

80 V, 100 mA NPN resistor-equipped transistors

---

**Fig. 20.** NHDTC144ET: Collector-emitter saturation voltage as a function of collector current; typical values

\[ V_{CE_{Sat}} (V) \]

\[ 1 \times 10^{-2} \]

\[ 1 \times 10^{-1} \]

\[ 1 \]

\[ 10 \]

\[ 10^2 \]

\[ I_C (mA) \]

\[ -1 \times 10^{-1} \]

\[ -1 \]

\[ -2 \times 10^{-1} \]

\[ 1 \]

\[ 2 \]

\[ 3 \]

\[ 4 \]

\[ 5 \]

\[ 6 \]

\[ 7 \]

\[ 8 \]

\[ 9 \]

\[ 10 \]

\[ 10^2 \]

\[ 10^3 \]

\[ 10^4 \]

\[ 10^5 \]

\[ 10^6 \]

\[ f \]

\[ 1 \times 10^{-3} \]

\[ 1 \times 10^{-2} \]

\[ 1 \]

\[ 10 \]

\[ 10^2 \]

\[ 10^3 \]

\[ 10^4 \]

\[ 10^5 \]

\[ 10^6 \]

\[ I_C (mA) \]

\[ V_{CE} (V) \]

\[ 0 \]

\[ 1 \]

\[ 2 \]

\[ 3 \]

\[ 4 \]

\[ 5 \]

\[ 6 \]

\[ 7 \]

\[ 8 \]

\[ 9 \]

\[ 10 \]

\[ 10^2 \]

\[ 10^3 \]

\[ 10^4 \]

\[ 10^5 \]

\[ 10^6 \]

\[ f = 1 \text{ MHz} \]

\[ V_{CE} = 5 \text{ V} \]

\[ T_{amb} = 25 \text{ °C} \]

---

\[ I_C/I_B = 20 \]

(1) \( T_{amb} = 100 \text{ °C} \)

(2) \( T_{amb} = 25 \text{ °C} \)

(3) \( T_{amb} = -40 \text{ °C} \)

---

**Fig. 21.** NHDTC144ET: Collector capacitance as a function of collector-base voltage; typical values

---

**Fig. 22.** Transition frequency as a function of collector current; typical values of built-in transistor

---

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11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

- Calculation of bias resistor 1 (R1)
  \[ R_1 = \frac{V(I_{i2}) - V(I_{i1})}{I_{i2} - I_{i1}} \]

- Calculation of bias resistor ratio (R2/R1)
  \[ \frac{R_2}{R_1} = \frac{V(I_{i4}) - V(I_{i3})}{R_1 \cdot (I_{i4} - I_{i3})} \]

![Fig. 23. PNP transistor: Resistor test circuit](aaa-020082)

Resistor test conditions

<table>
<thead>
<tr>
<th>Table 9. Resistor test conditions</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Type number</strong></td>
</tr>
<tr>
<td>NHDT114ET</td>
</tr>
<tr>
<td>NHDT124ET</td>
</tr>
<tr>
<td>NHDT144ET</td>
</tr>
</tbody>
</table>
12. Package outline

Fig. 24. Package outline TO-236AB (SOT23)
13. Soldering

![Reflow soldering footprint for TO-236AB (SOT23)](sot23_fr)

**Fig. 25.** Reflow soldering footprint for TO-236AB (SOT23)

![Wave soldering footprint for TO-236AB (SOT23)](sot23_fr)

**Fig. 26.** Wave soldering footprint for TO-236AB (SOT23)
14. Revision history

<table>
<thead>
<tr>
<th>Data sheet ID</th>
<th>Release date</th>
<th>Data sheet status</th>
<th>Change notice</th>
<th>Supersedes</th>
</tr>
</thead>
<tbody>
<tr>
<td>NHDTAC114_124_144ET_SER v.1</td>
<td>20200626</td>
<td>Product data sheet</td>
<td>-</td>
<td>-</td>
</tr>
</tbody>
</table>
15. Legal information

Data sheet status

<table>
<thead>
<tr>
<th>Document status</th>
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term "short data sheet" is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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